

# 74AHC259-Q100; 74AHCT259-Q100

8-bit addressable latch

Rev. 1 — 22 July 2013

Product data sheet

## 1. General description

The 74AHC259-Q100; 74AHCT259-Q100 is a high-speed Si-gate CMOS device and is pin compatible with Low-power Schottky TTL (LSTTL). It is specified in compliance with JEDEC standard No. 7-A.

The 74AHC259-Q100; 74AHCT259-Q100 is a high-speed 8-bit addressable latch designed for general purpose storage applications in digital systems. It is a multifunctional device capable of storing single-line data in eight addressable latches. It provides a 3-to-8 decoder and multiplexer function with active HIGH outputs (Q0 to Q7). It also incorporates an active LOW common reset ( $\overline{MR}$ ) for resetting all latches as well as an active LOW enable input ( $\overline{LE}$ ).

The 74AHC259-Q100; 74AHCT259-Q100 has four modes of operation:

- In the addressable latch mode, data on the data line (D) is written into the addressed latch. The addressed latch follows the data input with all non-addressed latches remaining in their previous states.
- In the memory mode, all latches remain in their previous states and are unaffected by the data or address inputs.
- In the 3-to-8 decoding or demultiplexing mode, the addressed output follows the state of the data input (D) with all other outputs in the LOW state.
- In the reset mode, all outputs are LOW and unaffected by the address inputs (A0 to A2) and data input (D).

When operating the 74AHC259-Q100; 74AHCT259-Q100 as an address latch, changing more than 1 bit of the address could impose a transient-wrong address. Therefore, only change more than 1 bit while in the memory mode.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

## 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - ◆ Specified from  $-40\text{ }^{\circ}\text{C}$  to  $+85\text{ }^{\circ}\text{C}$  and from  $-40\text{ }^{\circ}\text{C}$  to  $+125\text{ }^{\circ}\text{C}$
- Balanced propagation delays
- All inputs have Schmitt-trigger actions
- Combines demultiplexer and 8-bit latch
- Serial-to-parallel capability



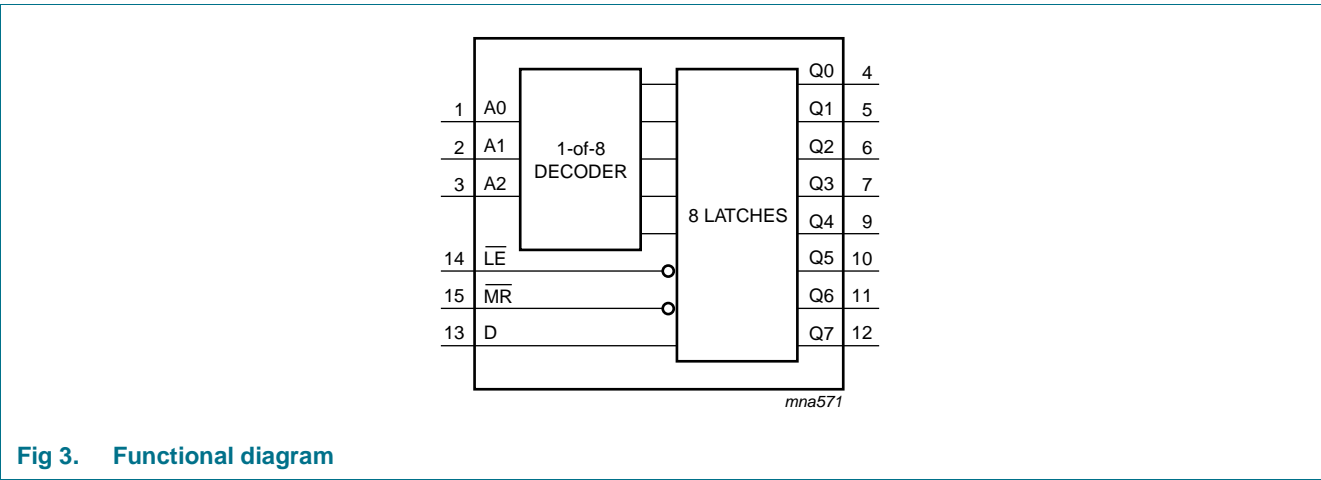
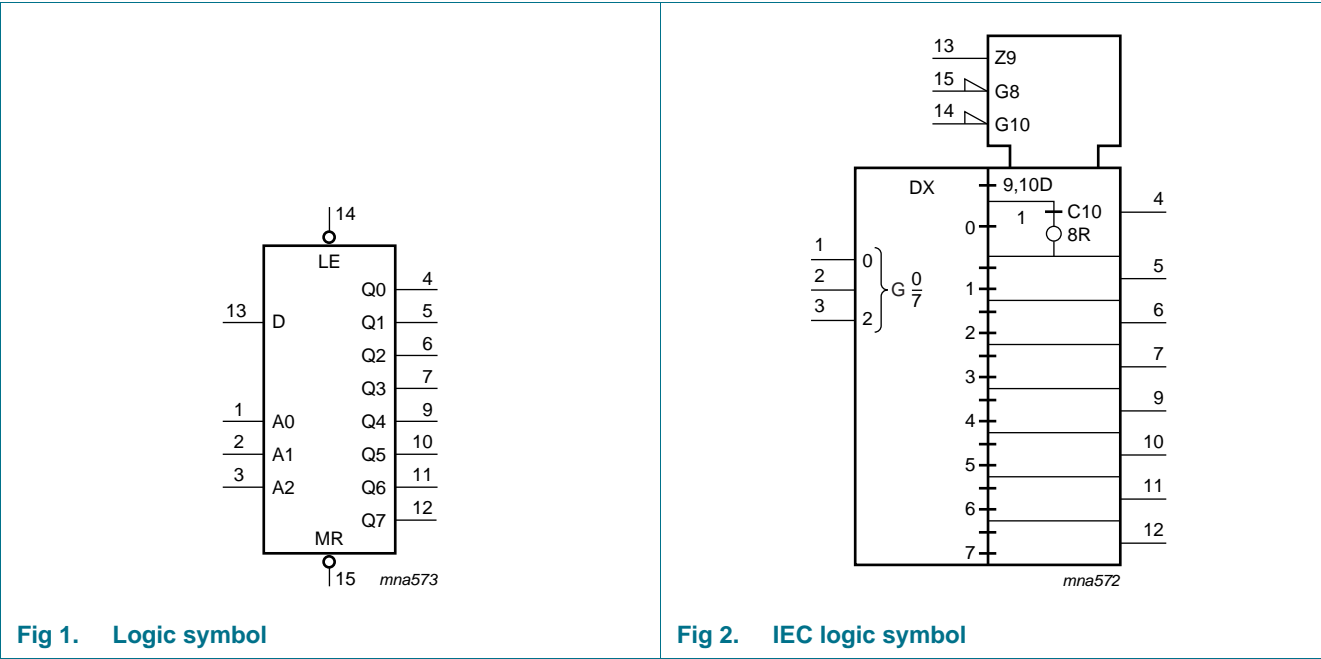
- Output from each storage bit available
- Random (addressable) data entry
- Easily expandable
- Common reset input
- Useful as a 3-to-8 active HIGH decoder
- Inputs accept voltages higher than  $V_{CC}$
- Input levels:
  - ◆ For 74AHC259-Q100: CMOS level
  - ◆ For 74AHCT259-Q100: TTL level
- ESD protection:
  - ◆ MIL-STD-883, method 3015 exceeds 2000 V
  - ◆ HBM JESD22-A114F exceeds 2000 V
  - ◆ MM JESD22-A115-A exceeds 200 V ( $C = 200$  pF,  $R = 0 \Omega$ )
- Multiple package options

### 3. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
<b>74AHC259-Q100</b>				
74AHC259D-Q100	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74AHC259PW-Q100	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1
<b>74AHCT259-Q100</b>				
74AHCT259D-Q100	-40 °C to +125 °C	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1
74AHCT259PW-Q100	-40 °C to +125 °C	TSSOP16	plastic thin shrink small outline package; 16 leads; body width 4.4 mm	SOT403-1

4. Functional diagram



5. Pinning information

5.1 Pinning

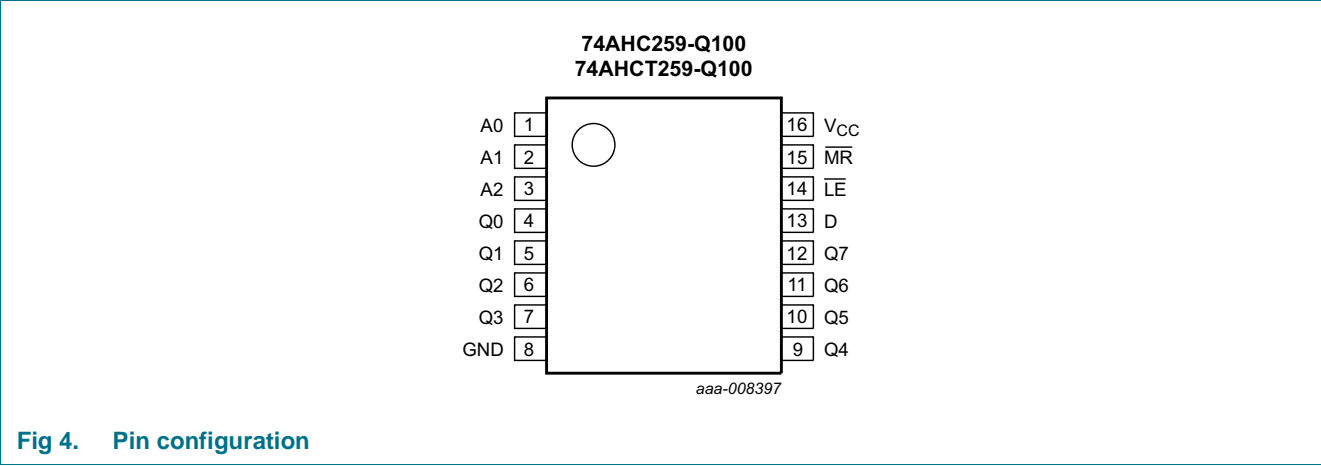


Fig 4. Pin configuration

5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
A0	1	address input
A1	2	address input
A2	3	address input
Q0	4	latch output
Q1	5	latch output
Q2	6	latch output
Q3	7	latch output
GND	8	ground (0 V)
Q4	9	latch output
Q5	10	latch output
Q6	11	latch output
Q7	12	latch output
D	13	data input
LE	14	latch enable input (active LOW)
MR	15	conditional reset input (active LOW)
VCC	16	supply voltage

## 6. Functional description

Table 3. Function table<sup>[1]</sup>

Operating mode	Input						Output							
	MR	LE	D	A0	A1	A2	Q0	Q1	Q2	Q3	Q4	Q5	Q6	Q7
Reset (clear)	L	H	X	X	X	X	L	L	L	L	L	L	L	L
Demultiplexer (active HIGH 8-channel) decoder (when D = H)	L	L	d	L	L	L	Q = d	L	L	L	L	L	L	L
			d	H	L	L	L	Q = d	L	L	L	L	L	L
			d	L	H	L	L	L	Q = d	L	L	L	L	L
			d	H	H	L	L	L	L	Q = d	L	L	L	L
			d	L	L	H	L	L	L	L	Q = d	L	L	L
			d	H	L	H	L	L	L	L	L	Q = d	L	L
			d	L	H	H	L	L	L	L	L	L	Q = d	L
			d	H	H	H	L	L	L	L	L	L	L	Q = d
Memory (no action)	H	H	X	X	X	X	q <sub>0</sub>	q <sub>1</sub>	q <sub>2</sub>	q <sub>3</sub>	q <sub>4</sub>	q <sub>5</sub>	q <sub>6</sub>	q <sub>7</sub>
Addressable latch	H	L	d	L	L	L	Q = d	q <sub>1</sub>	q <sub>2</sub>	q <sub>3</sub>	q <sub>4</sub>	q <sub>5</sub>	q <sub>6</sub>	q <sub>7</sub>
			d	H	L	L	q <sub>0</sub>	Q = d	q <sub>2</sub>	q <sub>3</sub>	q <sub>4</sub>	q <sub>5</sub>	q <sub>6</sub>	q <sub>7</sub>
			d	L	H	L	q <sub>0</sub>	q <sub>1</sub>	Q = d	q <sub>3</sub>	q <sub>4</sub>	q <sub>5</sub>	q <sub>6</sub>	q <sub>7</sub>
			d	H	H	L	q <sub>0</sub>	q <sub>1</sub>	q <sub>2</sub>	Q = d	q <sub>4</sub>	q <sub>5</sub>	q <sub>6</sub>	q <sub>7</sub>
			d	L	L	H	q <sub>0</sub>	q <sub>1</sub>	q <sub>2</sub>	q <sub>3</sub>	Q = d	q <sub>5</sub>	q <sub>6</sub>	q <sub>7</sub>
			d	H	L	H	q <sub>0</sub>	q <sub>1</sub>	q <sub>2</sub>	q <sub>3</sub>	q <sub>4</sub>	Q = d	q <sub>6</sub>	q <sub>7</sub>
			d	L	H	H	q <sub>0</sub>	q <sub>1</sub>	q <sub>2</sub>	q <sub>3</sub>	q <sub>4</sub>	q <sub>5</sub>	Q = d	q <sub>7</sub>
			H	H	H	H	q <sub>0</sub>	q <sub>1</sub>	q <sub>2</sub>	q <sub>3</sub>	q <sub>4</sub>	q <sub>5</sub>	q <sub>6</sub>	Q = d

[1] H = HIGH voltage level;

L = LOW voltage level;

X = don't care;

d = HIGH or LOW data one set-up time prior to the LOW-to-HIGH  $\overline{\text{LE}}$  transition;

q = lower case letter indicates the state of the referenced input one set-up time prior to the LOW-to-HIGH transition.

Table 4. Operating mode select table<sup>[1]</sup>

LE	MR	Mode
L	H	addressable latch
H	H	memory
L	L	active HIGH 8-channel demultiplexer
H	L	reset

[1] H = HIGH voltage level; L = LOW voltage level.

## 7. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	+7.0	V
$V_I$	input voltage		-0.5	+7.0	V
$I_{IK}$	input clamping current	$V_I < -0.5$ V	<sup>[1]</sup> -20	-	mA
$I_{OK}$	output clamping current	$V_O < -0.5$ V or $V_O > V_{CC} + 0.5$ V	<sup>[1]</sup> -20	+20	mA
$I_O$	output current	$V_O = -0.5$ V to $(V_{CC} + 0.5$ V)	-25	+25	mA
$I_{CC}$	supply current		-	+75	mA
$I_{GND}$	ground current		-75	-	mA
$T_{stg}$	storage temperature		-65	+150	°C
$P_{tot}$	total power dissipation	$T_{amb} = -40$ °C to +125 °C	<sup>[2]</sup> -	500	mW

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] For SO16 packages: above 70 °C the value of  $P_{tot}$  derates linearly at 8 mW/K.  
For TSSOP16 packages: above 60 °C the value of  $P_{tot}$  derates linearly at 5.5 mW/K.

## 8. Recommended operating conditions

Table 6. Operating conditions

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
74AHC259-Q100						
V <sub>CC</sub>	supply voltage		2.0	5.0	5.5	V
V <sub>I</sub>	input voltage		0	-	5.5	V
V <sub>O</sub>	output voltage		0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		−40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 3.0 V to 3.6 V	-	-	100	ns/V
		V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	20	ns/V
74AHCT259-Q100						
V <sub>CC</sub>	supply voltage		4.5	5.0	5.5	V
V <sub>I</sub>	input voltage		0	-	5.5	V
V <sub>O</sub>	output voltage		0	-	V <sub>CC</sub>	V
T <sub>amb</sub>	ambient temperature		−40	+25	+125	°C
Δt/ΔV	input transition rise and fall rate	V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	20	ns/V

## 9. Static characteristics

**Table 7. Static characteristics**

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	25 °C			–40 °C to +85 °C		–40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	Min	Max	
74AHC259-Q100										
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 2.0 V	1.5	-	-	1.5	-	1.5	-	V
		V <sub>CC</sub> = 3.0 V	2.1	-	-	2.1	-	2.1	-	V
		V <sub>CC</sub> = 5.5 V	3.85	-	-	3.85	-	3.85	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 2.0 V	-	-	0.5	-	0.5	-	0.5	V
		V <sub>CC</sub> = 3.0 V	-	-	0.9	-	0.9	-	0.9	V
		V <sub>CC</sub> = 5.5 V	-	-	1.65	-	1.65	-	1.65	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>								
		I <sub>O</sub> = –50 µA; V <sub>CC</sub> = 2.0 V	1.9	2.0	-	1.9	-	1.9	-	V
		I <sub>O</sub> = –50 µA; V <sub>CC</sub> = 3.0 V	2.9	3.0	-	2.9	-	2.9	-	V
		I <sub>O</sub> = –50 µA; V <sub>CC</sub> = 4.5 V	4.4	4.5	-	4.4	-	4.4	-	V
		I <sub>O</sub> = –4.0 mA; V <sub>CC</sub> = 3.0 V	2.58	-	-	2.48	-	2.40	-	V
V <sub>OL</sub>	LOW-level output voltage	I <sub>O</sub> = –8.0 mA; V <sub>CC</sub> = 4.5 V	3.94	-	-	3.80	-	3.70	-	V
		V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub>								
		I <sub>O</sub> = 50 µA; V <sub>CC</sub> = 2.0 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 50 µA; V <sub>CC</sub> = 3.0 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 50 µA; V <sub>CC</sub> = 4.5 V	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 4.0 mA; V <sub>CC</sub> = 3.0 V	-	-	0.36	-	0.44	-	0.55	V
I <sub>I</sub>	input leakage current	I <sub>O</sub> = 8.0 mA; V <sub>CC</sub> = 4.5 V	-	-	0.36	-	0.44	-	0.55	V
		V <sub>I</sub> = 5.5 V or GND; V <sub>CC</sub> = 0 V to 5.5 V	-	-	0.1	-	1.0	-	2.0	µA
I <sub>CC</sub>	supply current	V <sub>I</sub> = V <sub>CC</sub> or GND; I <sub>O</sub> = 0 A; V <sub>CC</sub> = 5.5 V	-	-	4.0	-	40	-	80	µA
C <sub>I</sub>	input capacitance	V <sub>I</sub> = V <sub>CC</sub> or GND	-	3	10	-	10	-	10	pF
C <sub>O</sub>	output capacitance		-	4	-	-	-	-	-	pF
74AHCT259-Q100										
V <sub>IH</sub>	HIGH-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	2.0	-	-	2.0	-	2.0	-	V
V <sub>IL</sub>	LOW-level input voltage	V <sub>CC</sub> = 4.5 V to 5.5 V	-	-	0.8	-	0.8	-	0.8	V
V <sub>OH</sub>	HIGH-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>CC</sub> = 4.5 V								
		I <sub>O</sub> = –50 µA	4.4	4.5	-	4.4	-	4.4	-	V
		I <sub>O</sub> = –8.0 mA	3.94	-	-	3.80	-	3.70	-	V
V <sub>OL</sub>	LOW-level output voltage	V <sub>I</sub> = V <sub>IH</sub> or V <sub>IL</sub> ; V <sub>CC</sub> = 4.5 V								
		I <sub>O</sub> = 50 µA	-	0	0.1	-	0.1	-	0.1	V
		I <sub>O</sub> = 8.0 mA	-	-	0.36	-	0.44	-	0.55	V

**Table 7.** Static characteristics ...continued

At recommended operating conditions; voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	25 °C			–40 °C to +85 °C		–40 °C to +125 °C		Unit
			Min	Typ	Max	Min	Max	Min	Max	
$I_I$	input leakage current	$V_I = 5.5\text{ V}$ or GND; $V_{CC} = 0\text{ V}$ to 5.5 V	-	-	0.1	-	1.0	-	2.0	$\mu\text{A}$
$I_{CC}$	supply current	$V_I = V_{CC}$ or GND; $I_O = 0\text{ A}$ ; $V_{CC} = 5.5\text{ V}$	-	-	4.0	-	40	-	80	$\mu\text{A}$
$\Delta I_{CC}$	additional supply current	per input pin; $V_I = V_{CC} - 2.1\text{ V}$ ; other pins at $V_{CC}$ or GND; $I_O = 0\text{ A}$ ; $V_{CC} = 4.5\text{ V}$ to 5.5 V	-	-	1.35	-	1.5	-	1.5	mA
$C_I$	input capacitance	$V_I = V_{CC}$ or GND	-	3	10	-	10	-	10	pF
$C_O$	output capacitance		-	4	-	-	-	-	-	pF

## 10. Dynamic characteristics

**Table 8.** Dynamic characteristicsVoltages are referenced to GND (ground = 0 V); for test circuit, see [Figure 11](#).

Symbol	Parameter	Conditions	25 °C			–40 °C to +85 °C		–40 °C to +125 °C		Unit
			Min	Typ <sup>[1]</sup>	Max	Min	Max	Min	Max	

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$t_{pd}$	propagation delay	D to Qn; see <a href="#">Figure 5</a>	<sup>[2]</sup>							
		$V_{CC} = 3.0\text{ V}$ to 3.6 V								
		$C_L = 15\text{ pF}$	-	5.8	11.5	1.0	13.5	1.0	15.0	ns
		$C_L = 50\text{ pF}$	-	7.3	14.5	1.0	17.0	1.0	18.5	ns
		$V_{CC} = 4.5\text{ V}$ to 5.5 V								
		$C_L = 15\text{ pF}$	-	4.1	7.5	1.0	9.0	1.0	10.0	ns
		$C_L = 50\text{ pF}$	-	5.3	9.5	1.0	11.0	1.0	12.0	ns
		An to Qn; see <a href="#">Figure 6</a>	<sup>[2]</sup>							
		$V_{CC} = 3.0\text{ V}$ to 3.6 V								
		$C_L = 15\text{ pF}$	-	7.5	14.5	1.0	17.0	1.0	18.5	ns
		$C_L = 50\text{ pF}$	-	9.1	18.0	1.0	21.0	1.0	23.0	ns
		$V_{CC} = 4.5\text{ V}$ to 5.5 V								
		$C_L = 15\text{ pF}$	-	5.3	9.5	1.0	11.5	1.0	12.5	ns
		$C_L = 50\text{ pF}$	-	6.5	11.5	1.0	13.5	1.0	15.0	ns
		$\overline{\text{LE}}$ to Qn; see <a href="#">Figure 7</a>	<sup>[2]</sup>							
		$V_{CC} = 3.0\text{ V}$ to 3.6 V								
		$C_L = 15\text{ pF}$	-	6.2	12.0	1.0	14.0	1.0	15.2	ns
		$C_L = 50\text{ pF}$	-	7.7	15.5	1.0	17.5	1.0	19.0	ns
		$V_{CC} = 4.5\text{ V}$ to 5.5 V								
		$C_L = 15\text{ pF}$	-	4.3	8.0	1.0	9.5	1.0	10.5	ns
		$C_L = 50\text{ pF}$	-	5.5	10.0	1.0	11.5	1.0	12.5	ns



**Table 8. Dynamic characteristics ...continued**Voltages are referenced to GND (ground = 0 V); for test circuit, see [Figure 11](#).

Symbol	Parameter	Conditions	25 °C			–40 °C to +85 °C		–40 °C to +125 °C		Unit
			Min	Typ <sup>[1]</sup>	Max	Min	Max	Min	Max	
$t_{pd}$	propagation delay	$\overline{MR}$ to Qn; see <a href="#">Figure 8</a> <sup>[3]</sup>								
		$V_{CC} = 3.0\text{ V to }3.6\text{ V}$								
		$C_L = 15\text{ pF}$	-	5.4	10.5	1.0	12.5	1.0	13.5	ns
		$C_L = 50\text{ pF}$	-	7.0	13.5	1.0	15.5	1.0	17.0	ns
		$V_{CC} = 4.5\text{ V to }5.5\text{ V}$								
		$C_L = 15\text{ pF}$	-	3.9	7.0	1.0	8.5	1.0	9.5	ns
$t_W$	pulse width	$\overline{LE}$ HIGH or LOW; see <a href="#">Figure 7</a>								
		$V_{CC} = 3.0\text{ V to }3.6\text{ V}$	5.0	-	-	5.0	-	5.0	-	ns
		$V_{CC} = 4.5\text{ V to }5.5\text{ V}$	5.0	-	-	5.0	-	5.0	-	ns
		$\overline{MR}$ LOW; see <a href="#">Figure 8</a>								
		$V_{CC} = 3.0\text{ V to }3.6\text{ V}$	5.0	-	-	5.0	-	5.0	-	ns
		$V_{CC} = 4.5\text{ V to }5.5\text{ V}$	5.0	-	-	5.0	-	5.0	-	ns
$t_{su}$	set-up time	D, An to $\overline{LE}$ ; see <a href="#">Figure 9</a> and <a href="#">Figure 10</a>								
		$V_{CC} = 3.0\text{ V to }3.6\text{ V}$	4.0	-	-	4.0	-	4.0	-	ns
		$V_{CC} = 4.5\text{ V to }5.5\text{ V}$	4.0	-	-	4.0	-	4.0	-	ns
$t_h$	hold time	D, An to $\overline{LE}$ ; see <a href="#">Figure 9</a> and <a href="#">Figure 10</a>								
		$V_{CC} = 3.0\text{ V to }3.6\text{ V}$	1.0	-	-	1.0	-	1.0	-	ns
		$V_{CC} = 4.5\text{ V to }5.5\text{ V}$	1.0	-	-	1.0	-	1.0	-	ns
$C_{PD}$	power dissipation capacitance	$f_i = 1\text{ MHz}$ ; $V_I = \text{GND to }V_{CC}$ <sup>[4]</sup>	-	13	-	-	-	-	-	pF

**74AHCT259-Q100;  $V_{CC} = 4.5\text{ V to }5.5\text{ V}$** 

$t_{pd}$	propagation delay	D to Qn; see <a href="#">Figure 5</a> <sup>[2]</sup>								
		$C_L = 15\text{ pF}$	-	4.1	7.5	1.0	9.0	1.0	10.0	ns
		$C_L = 50\text{ pF}$	-	5.4	9.5	1.0	11.0	1.0	12.0	ns
		An to Qn; see <a href="#">Figure 6</a> <sup>[2]</sup>								
		$C_L = 15\text{ pF}$	-	5.5	9.5	1.0	11.5	1.0	12.5	ns
		$C_L = 50\text{ pF}$	-	6.6	12.0	1.0	14.0	1.0	15.5	ns
		$\overline{LE}$ to Qn; see <a href="#">Figure 7</a> <sup>[2]</sup>								
		$C_L = 15\text{ pF}$	-	4.3	8.0	1.0	9.5	1.0	10.4	ns
		$C_L = 50\text{ pF}$	-	5.5	10.0	1.0	12.0	1.0	13.0	ns
		$\overline{MR}$ to Qn; see <a href="#">Figure 8</a> <sup>[3]</sup>								
		$C_L = 15\text{ pF}$	-	3.9	7.0	1.0	8.5	1.0	9.5	ns
		$C_L = 50\text{ pF}$	-	5.1	9.0	1.0	10.5	1.0	11.5	ns
$t_W$	pulse width	$\overline{LE}$ HIGH or LOW; see <a href="#">Figure 7</a>	5.0	-	-	5.0	-	5.0	-	ns
		$\overline{MR}$ LOW; see <a href="#">Figure 8</a>	5.0	-	-	5.0	-	5.0	-	ns

**Table 8. Dynamic characteristics ...continued**

Voltages are referenced to GND (ground = 0 V); for test circuit, see [Figure 11](#).

Symbol	Parameter	Conditions	25 °C			–40 °C to +85 °C		–40 °C to +125 °C		Unit
			Min	Typ <sup>[1]</sup>	Max	Min	Max	Min	Max	
$t_{su}$	set-up time	D, An to $\overline{LE}$ ; see <a href="#">Figure 9</a> and <a href="#">Figure 10</a>	4.0	-	-	4.0	-	4.0	-	ns
$t_h$	hold time	D, An to $\overline{LE}$ ; see <a href="#">Figure 9</a> and <a href="#">Figure 10</a>	1.0	-	-	1.0	-	1.0	-	ns
$C_{PD}$	power dissipation capacitance	$f_i = 1$ MHz; $V_I = \text{GND to } V_{CC}$ <a href="#">[4]</a>	-	17	-	-	-	-	-	pF

[1] Typical values are measured at nominal supply voltage ( $V_{CC} = 3.3$  V and  $V_{CC} = 5.0$  V).

[2]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .

[3]  $t_{pd}$  is the same as  $t_{PHL}$  only.

[4]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu\text{W}$ ).

$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$  where:

$f_i$  = input frequency in MHz;

$f_o$  = output frequency in MHz;

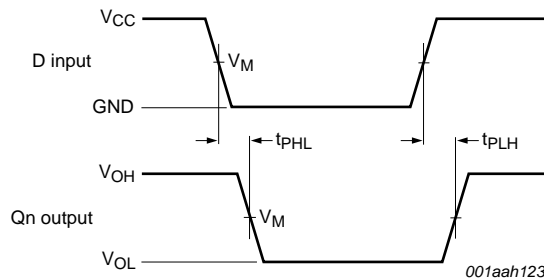
$C_L$  = output load capacitance in pF;

$V_{CC}$  = supply voltage in V;

$N$  = number of inputs switching;

$\Sigma(C_L \times V_{CC}^2 \times f_o)$  = sum of the outputs.

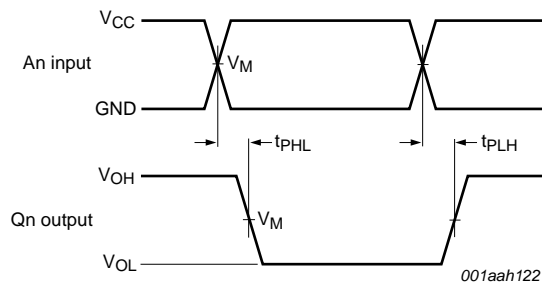
## 11. Waveforms



Measurement points are given in [Table 9](#).

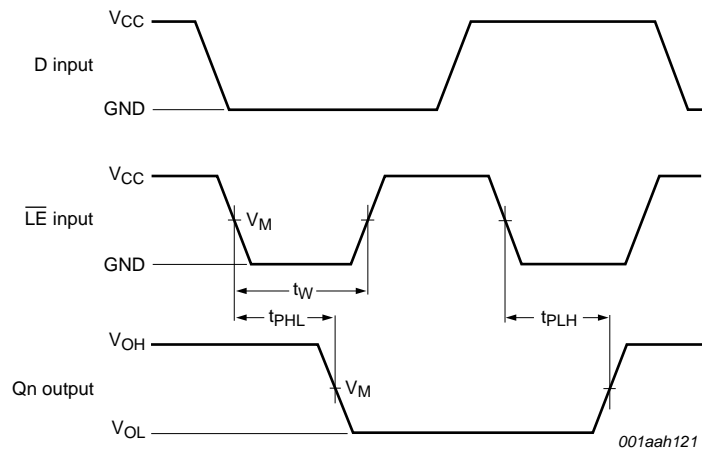
$V_{OL}$  and  $V_{OH}$  are typical voltage output levels that occur with the output load.

**Fig 5. Data input to output propagation delays**



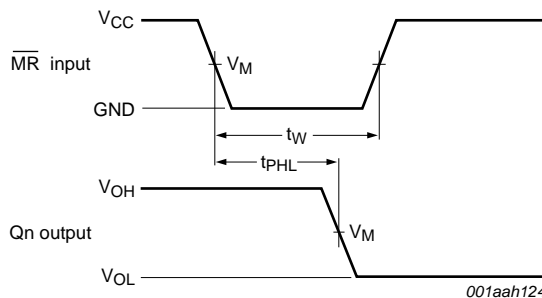
Measurement points are given in [Table 9](#).  
 $V_{OL}$  and  $V_{OH}$  are typical voltage output levels that occur with the output load.

**Fig 6. Address input to output propagation delays**



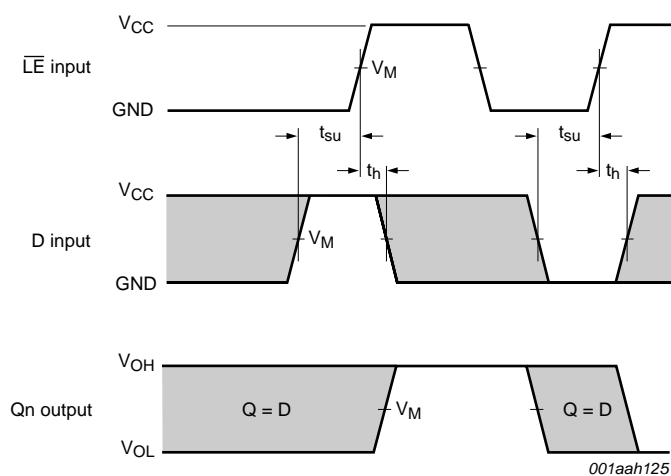
Measurement points are given in [Table 9](#).  
 $V_{OL}$  and  $V_{OH}$  are typical voltage output levels that occur with the output load.

**Fig 7. Enable input to output propagation delays and pulse width**



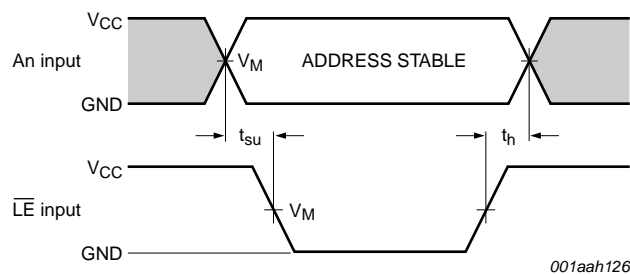
Measurement points are given in [Table 9](#).  
 $V_{OL}$  and  $V_{OH}$  are typical voltage output levels that occur with the output load.

**Fig 8. Conditional reset input to output propagation delays**



Measurement points are given in [Table 9](#).  
The shaded areas indicate when the input is permitted to change for predictable output performance.  
 $V_{OL}$  and  $V_{OH}$  are typical voltage output levels that occur with the output load.

Fig 9. Data input to latch enable input set-up and hold times

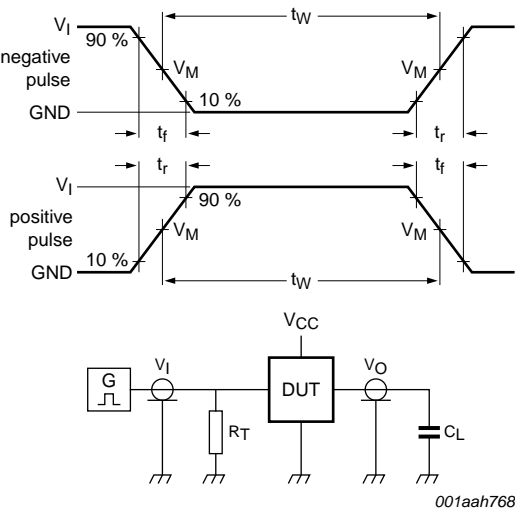


Measurement points are given in [Table 9](#).  
The shaded areas indicate when the input is permitted to change for predictable output performance.  
 $V_{OL}$  and  $V_{OH}$  are typical voltage output levels that occur with the output load.

Fig 10. Address input to latch enable input set-up and hold times

Table 9. Measurement points

Type	Input	Output
	$V_M$	$V_M$
74AHC259-Q100	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
74AHCT259-Q100	1.5 V	$0.5 \times V_{CC}$



Test data is given in [Table 10](#).  
Definitions test circuit:  
 $R_T$  = termination resistance should be equal to output impedance  $Z_o$  of the pulse generator.  
 $C_L$  = load capacitance including jig and probe capacitance.

Fig 11. Load circuitry for measuring switching times

Table 10. Test data

Type	Input		Load	Test
	$V_I$	$t_r, t_f$	$C_L$	
74AHC259-Q100	$V_{CC}$	$\leq 3.0 \text{ ns}$	15 pF, 50 pF	$t_{PLH}, t_{PHL}$
74AHCT259-Q100	3.0 V	$\leq 3.0 \text{ ns}$	15 pF, 50 pF	$t_{PLH}, t_{PHL}$

12. Package outline

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1

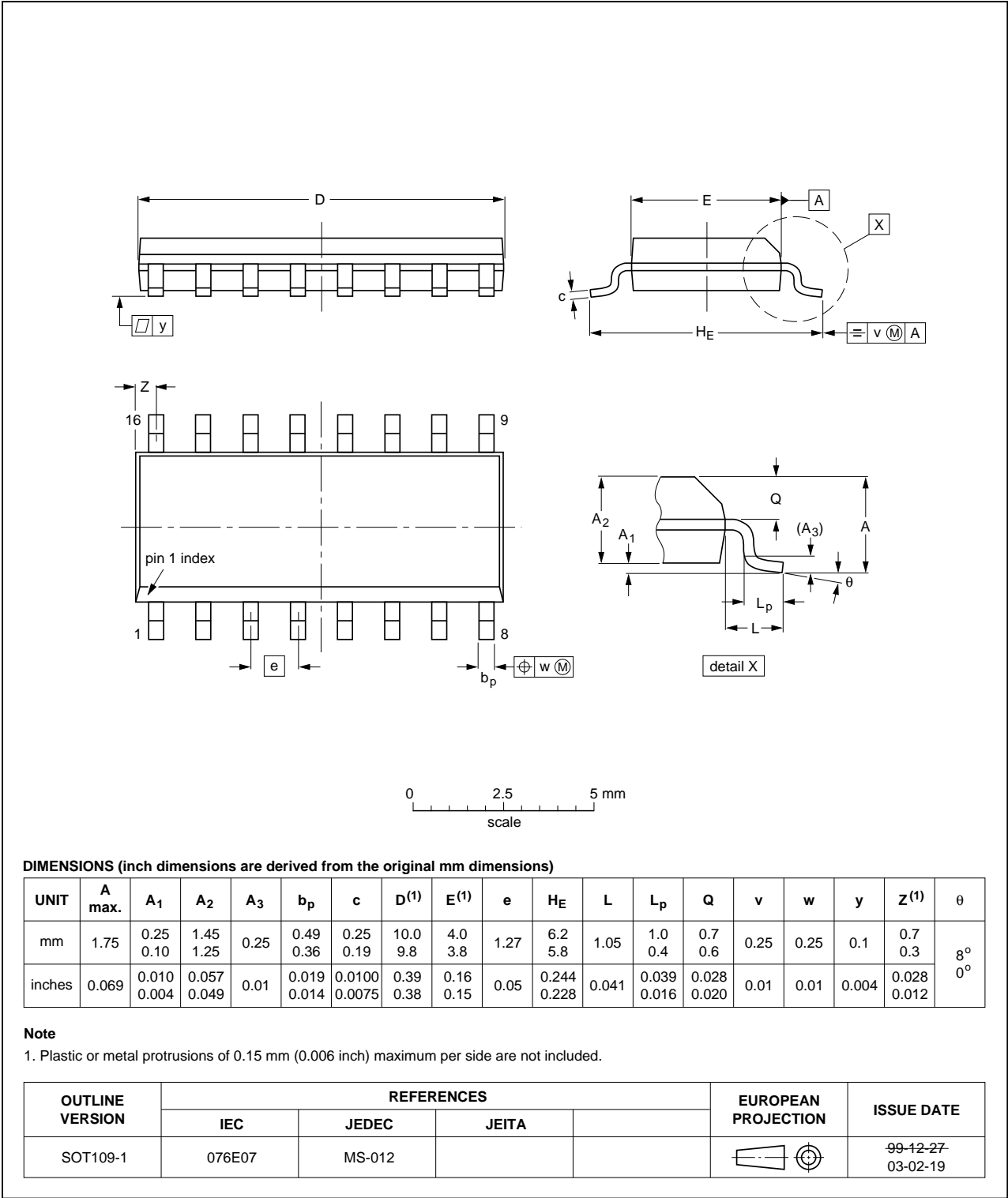


Fig 12. Package outline SOT109-1 (SO16)

TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1

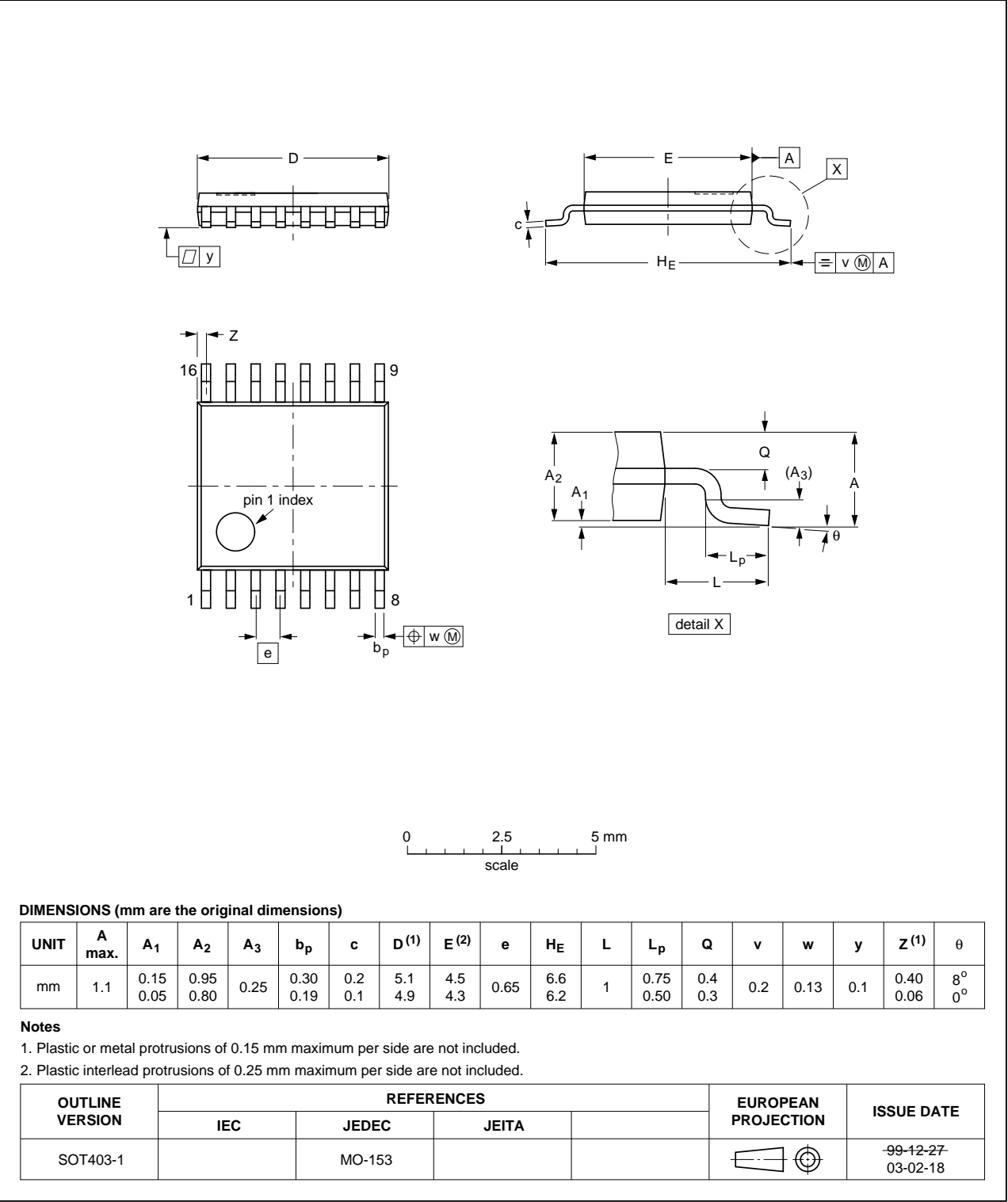


Fig 13. Package outline SOT403-1 (TSSOP16)

## 13. Abbreviations

Table 11. Abbreviations

Acronym	Description
CDM	Charged Device Model
CMOS	Complementary Metal-Oxide Semiconductor
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
MIL	Military
TTL	Transistor-Transistor Logic

## 14. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AHC_AHCT259_Q100 v.1	20130722	Product data sheet	-	-



## 15. Legal information

### 15.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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[2] The term 'short data sheet' is explained in section "Definitions".

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